

SP1100SA

ROHS

Description

DO-214AA P Series solid state protection thyristor protect telecommunications equipment such as modems, line cards, fax machines, and other CPE.

P Series devices are used to enable equipment to meet various regulatory requirements including GR 1089, ITU K.20, K.21 and K.45, IEC 60950, UL 60950, and TIA-968 (formerly known as FCC Part 68).

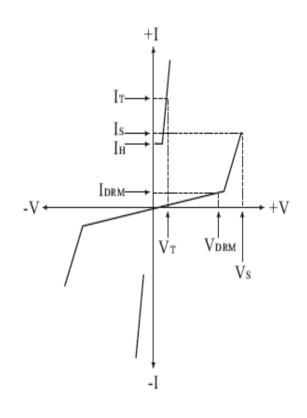


Compared to surge suppression using other technologies, P Series devices offer absolute surge protection regardless of the surge current available and the rate of applied voltage (dv/dt). P Series devices:

- Cannot be damaged by voltage
- Eliminate hysteresis and heat dissipation typically found with clamping devices
- Eliminate voltage overshoot caused by fast-rising transients
- Are non-degenerative
- Will not fatigu
- · Have low capacitance, making them ideal for high-speed transmission equipment

Electrical Parameters

Parameter	Definition				
Co	Off-state Capacitance — typical capacitance				
	measured in off state				
di/dt	Rate of Rise of Current — maximum rated value of				
	the acceptable rate of rise in current over time				
\mathbf{I}^{s}	Switching Current — maximum current required to				
	switch to on state				
\mathbf{I} DRM	Leakage Current — maximum peak off-state current				
	measured at VDRM				
$\mathbf{I}^{_{\mathrm{H}}}$	Holding Current — minimum current required to				
	maintain on state				
I PP	Peak Pulse Current — maximum rated peak impulse				
	current				
I T	On-state Current — maximum rated continuous				
	on-state current				
ITSM	Peak One-cycle Surge Current — maximum rated				
	one-cycle AC current				
V s	Switching Voltage — maximum voltage prior to				
	switching to on state				
V DRM	Peak Off-state Voltage — maximum voltage that can				
	be applied while maintaining off state				
V F	On-state Forward Voltage — maximum forward				
	voltage measured at rated on-state current				
V T	On-state Voltage — maximum voltage measured at				
	rated on-state current				





Over-voltage Protection Thyristor				SP	SP1100SA			
ElectricalCha	racterist	ics						
Part Number*	Vdrm Volts	Vs Volts	V _T Volts	Idrm µ Amps	Is mAmps	It Amps	Iн mAmps	Co pF
SP1100SA	90	130	4	5	800	2. 2	150	35

^{*} For surge ratings, see table below.

Notes:

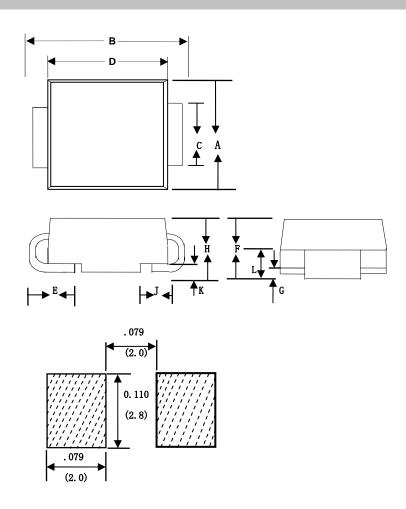
- All measurements are made at an ambient temperature of 25°C. IPP applies to -40°C through +85°C temperature range.
- Off-state capacitance (Co) is measured at 1 MHz with a 2 V bias and is typical value.

Surge Rat:	ings						
Series	Ipp 2/10 µs Amps	IPP 8/20 µs Amps	IPP 10/160 μs Amps	IPP 10/560 µs Amps	IPP 10/1000 μs Amps	Itsm 60 Hz Amps	di/dt Amps/μs
A	150	150	90	50	45	20	500

Thermal Considerations				
Package DO-214AA/SMB	Symbol	Parameter	Value	Unit
	$T_{ m J}$	Operating Junction Temperature	-40 to +150	$^{\circ}$ C
	Ts	Storage Temperature Range	-40 to +150	$^{\circ}$
	R ө JA	unction to Ambient on printed circuit	120	\mathbb{C}/\mathbb{W}

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Dimensions



SMB

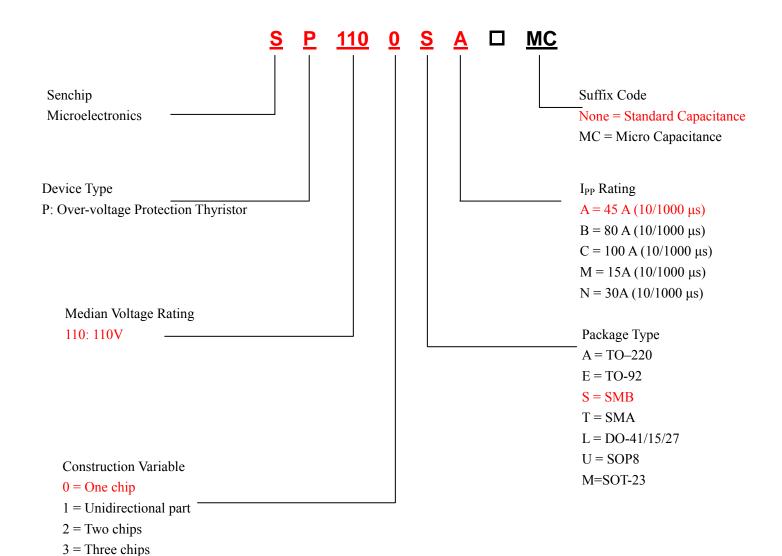
Dimension	In	ches	Millimeters		
	MIN	MAX	MIN	MAX	
A	0. 134	0. 155	3. 40	3. 94	
В	0. 205	0. 22	5. 21	5. 59	
С	0. 075	0. 083	1. 90	2. 11	
D	0. 166	0. 185	4. 22	4. 70	
Е	0. 036	0. 056	0. 91	1. 42	
F	0.073	0. 087	1.85	2. 2	
G	0.002	0.008	0. 05	0. 20	
Н	0. 077	0.094	1. 95	2. 40	
J	0.043	0. 053	1. 09	1. 35	
K	0.008	0.014	0. 20	0. 35	
L	0. 039	0.049	0. 99	1. 24	



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Description of Part Number

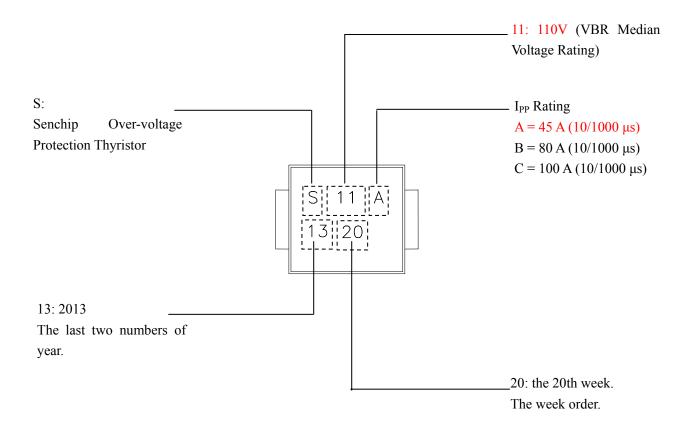




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Description of Marking





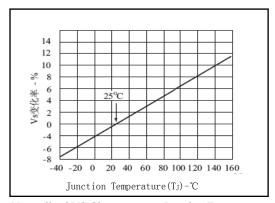
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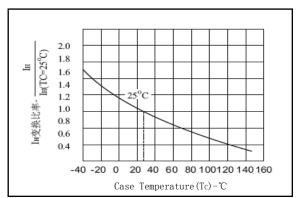
Summary of Packing Options

Package Type	Description	Packing Quantity	Industry Standard
DO-214AA SMB	Embossed Carrier Reel Pack	2500 PCS	EIA RS-481

Thermal Derating Curves



Normalized VS Change versus Junction Temperature



Normalized DC Holding Current versus Case Temperature



E313687